

RoHS

COMPLIANT HALOGEN

Available

N-Channel 30-V (D-S) MOSFET

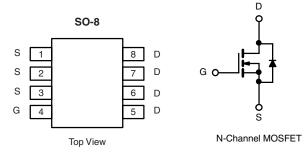
PRODUCT SUMMARY					
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)			
30	0.0030 at V _{GS} = 10 V	25			
	0.0040 at V_{GS} = 4.5 V	22			

FEATURES

- Halogen-free According to IEC 61249-2-21
 Available
- TrenchFET[®] Gen II
- Ultra Low On-Resistance Using High Density TrenchFET Power MOSFET Technology



- Synchronous Buck Low-Side
 - Notebook
 - Server
 - Workstation
- Synchronous Rectifier-POL



Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	30		V
Gate-Source Voltage		V _{GS}	± 20		v
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	– I _D	25	17	
	T _A = 70 °C		20	13	
Pulsed Drain Current (10 µs Pulse Width)		I _{DM}	70		А
Continuous Source Current (Diode Conduction) ^a		۱ _S	2.9	1.3	
Avalanche Current		I _{AS}	50		
	T _A = 25 °C	P _D	3.5	1.6	W
Maximum Power Dissipation ^a	T _A = 70 °C	' D	2.2	1	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum hursting to Auchienta	t ≤ 10 s	- R _{thJA}	29	35	
Maximum Junction-to-Ambient ^a	Steady State		67	80	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	13	16	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	· · ·		·	·	· · · · · · · · · · · · · · · · · · ·		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1.0		3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zava Cata Valtaga Drain Current		$V_{DS} = 30 V, V_{GS} = 0 V$			1		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 30 V, V_{GS} = 0 V, T_{J} = 55 °C			5	μA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	30			А	
	D	V _{GS} = 10 V, I _D = 25 A		0.003		0	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 22 \text{ A}$		0.004		Ω	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 25 \text{ A}$		110		S	
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S}$ = 2.9 A, $V_{\rm GS}$ = 0 V		0.72	1.1	V	
Dynamic ^b							
Input Capacitance	C _{iss}			6500			
Output Capacitance	C _{oss}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 20 A		930		pF	
Reverse Transfer Capacitance	C _{rss}			610		1	
Total Gate Charge	Qg			45	70		
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 20 A		20		nC	
Gate-Drain Charge	Q _{gd}			16			
Gate Resistance	Rg	f = 1.0 MHz		1.1		Ω	
Turn-On Delay Time	t _{d(on)}			27	40		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		21	35		
Turn-Off Delay Time	t _{d(off)}	$\rm I_D \cong 1$ A, $\rm V_{GEN}$ = 10 V, $\rm R_g$ = 6 Ω		107	160	ns	
Fall Time	t _f			43	65		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, dI/dt = 100 A/μs		45	70		

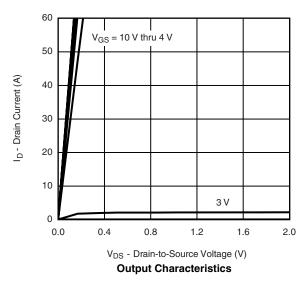
Notes:

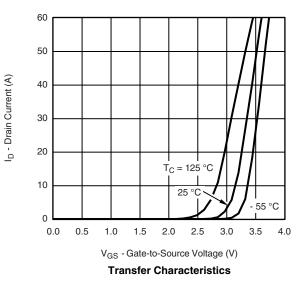
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

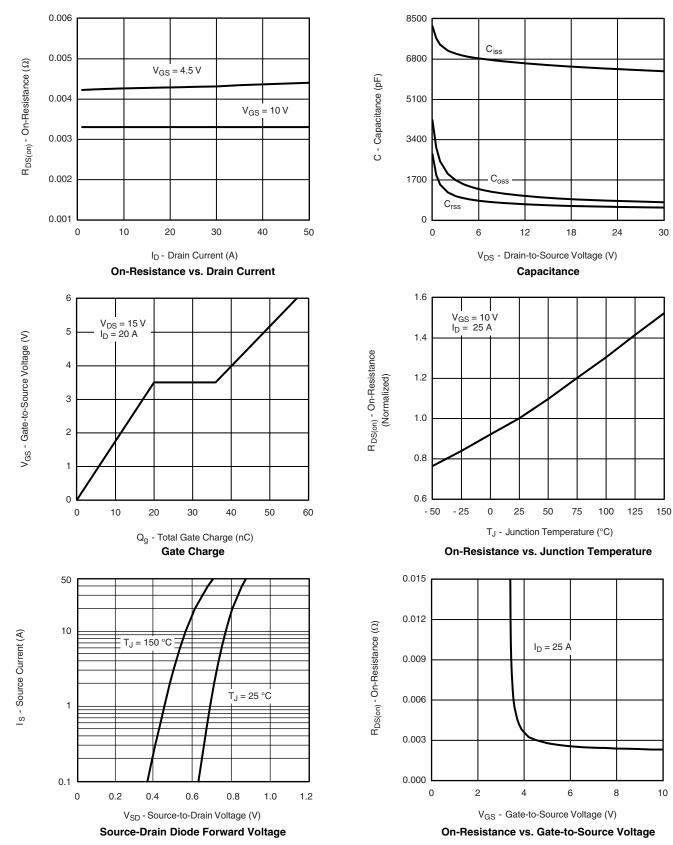
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





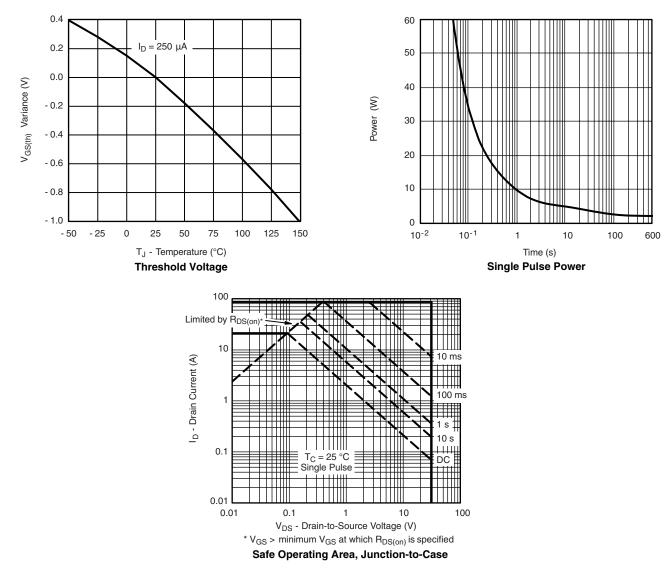


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

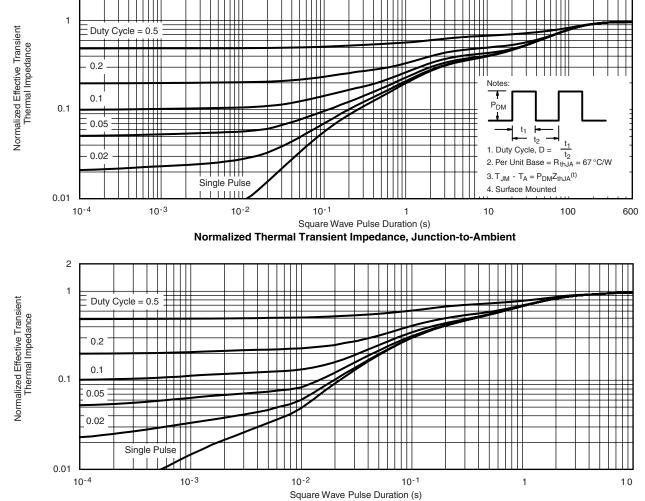




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



2



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

Normalized Thermal Transient Impedance, Junction-to-Foot

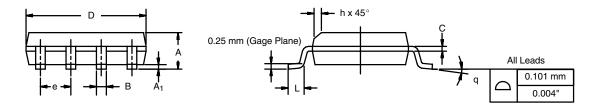
Bsemi

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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012

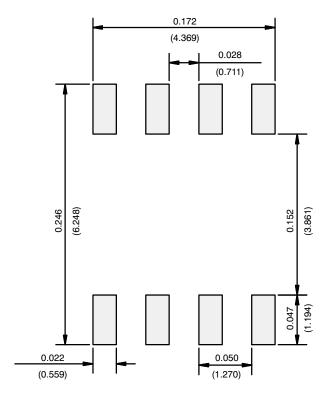




	MILLIM	IETERS	INCHES			
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)



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